VACUUMSCHMELZE		Specification Item no.:				T60404-F	T60404-P4640-X256		
-no.: K2692	28	1700A Current Sensor for ±24V supply with a transformation ratio of K _N =1:5000 for electric current measurement:						08.09.2021	
		DC, AC, pulsed primary circuit (, mixed, with high power) and	a galvanic isolation d secondary circuit (between electronic ci	rcuit)			
ustomer: Si	tandard t	type		Customers Part	no.:		Page	1 von 8	
lectrical Dat	ta – Rati	ngs							
IPN	Prima	ary nominal r.m.s.	. current			1700		А	
Rм ¹⁾	Meas	suring resistance	for IPN DC @ 8	5°C		0 30)	Ω	
Isn	Seco	ndary nominal r.n	n.s. or DC cur	rent		340		mA	
K _N ²⁾	Turns	s ratio				(1): 50	00		
¹⁾ for the max. m	easuring rar	nge depending on R _M j	please refer to Fig	J.2					
²⁾ first number in	brackets rep	presents the count of	primary turns guid	led through the primary	opening of th	e sensor			
<u> Accuracy – D</u>	<u>ynamic</u>	performance of	data						
					min.	typ.	max.	Unit	
P,max ¹⁾	meas	suring range @ R _N	$A = 1 \Omega; \vartheta_A = 20^\circ$	C; U _C =±24V	3400			A	
		@ R _N	$A = 1 \Omega; \vartheta_A = 85^\circ$	C; U _C =±24V	2750			A	
X	Accu	racy @ I_{PN} for $\vartheta_{A}=2$	25°C				0.3	%	
X _{Ti}	Temp	Derature drift of X	($\partial \theta_{A} = -40 \dots +$	+85 °C (secondary)			0.1	%	
εL	Linea	arity					0.1	%	
IS0	Offse	et current (second	ary) @ I _P =0A, ·	θ _A = 25°C			0.1	mA	
IS0H	Hyste	eresis current (se	condary)			0.5	0.1	mA	
lr Λ+ (I)	Resp	onse lime @ 90%	OT I _{PN}	A (< 0.5	0.5	μs	
Δl (IP, max)	Delay	y time @ 10% of I _P	N (at di/dt = 600	A/μS)	DC 100		0.5	μs kU=	
IBW	Frequ	Jency bandwidth	(smail signal)		DC100			KITZ	
9 , 1)	Ambi	ent operating tem	nerature		<mark>min.</mark> -40	typ.	max. +85	<mark>Unit</mark> ଂମ	
ϑ _A ¹⁾ ϑs	Ambi Ambi	ent operating tem	nperature erature acc. VA	C M3101	<mark>min.</mark> -40 -45	typ.	max. +85 +100	Unit °C °C	
ϑ _A ¹) ϑ _S m	Ambi Ambi Mass	ent operating tem ent storage temp	nperature erature _{acc.} VA	C M3101	<mark>min.</mark> -40 -45	typ. 550	max. +85 +100	Unit °C °C q	
ϑ _A ¹⁾ ϑs m U _C	Ambi Ambi Mass Supp	ent operating tem ent storage temp s ly voltage	nperature erature _{acc.} VA	C M3101	<mark>min.</mark> -40 -45 ±22.8	typ. 550 ±24	max. +85 +100 ±25.2	Unit °C °C g V	
ϑ _A ¹⁾ ϑ _S m Uc Ico	Ambi Ambi Mass Supp Curre	ent operating tem ent storage temp dy voltage ent consumption f	nperature erature acc. VA for Ip = 0A	C M3101	<mark>min.</mark> -40 -45 ±22.8	typ. 550 ±24 ±31	max. +85 +100 ±25.2	Unit °C °C g V mA	
ອ _A ¹⁾ ອ _S M Uc Ico Ico ²⁾	Ambi Ambi Mass Supp Curre Curre	ent operating tem ent storage temp ly voltage ent consumption f ent consumption f	nperature erature acc. VA or Ip = 0A or I _{PN} = 1500/	C M3101	min. -40 -45 ±22.8 270	typ. 550 ±24 ±31 310	max. +85 +100 ±25.2 375	Unit °C °C g V mA mA	
ϑA 1) ϑS m Uc Ico IcN 2) 1) The temperatu 2) Due to the Class The specified w the resistor RM	Ambi Ambi Mass Supp Curre Curre curre ss-D final sta vide range of connected	ent operating tem ent storage temp ly voltage ent consumption f ent consumption f nsor surface at any po age used for generatin f the supply current is to the sensor output.	aperature erature acc. VA for $Ip = 0A$ or $I_{PN} = 1500/$ sition must not ex ng the compensat reasoned by depo	C M3101 A ceed 105°C ion current, the supply o endencies on ambient o	min. -40 -45 ±22.8 270 Current I _{CN} (Ic pperating temp	typ. 550 ±24 ±31 310 @ I _P = I _{PN}) i: operature 9 _A	max. +85 +100 ±25.2 375 s lower than I _{SN} . and the value of	Unit °C °C g V mA mA	
ϑA 1) ϑS m UC Ico ICN 2) 1) The temperatu 2) Due to the Cla The specified w the resistor RM Sclear 3)	Ambi Ambi Mass Supp Curre Curre re of the ser ss-D final sta vide range of connected	ent operating tem ent storage temp dy voltage ent consumption f ent consumption f nsor surface at any po age used for generating the supply current is to the sensor output. rance distance	perature erature acc. VA or $Ip = 0A$ or $I_{PN} = 1500/$ sition must not ex ng the compensat reasoned by depe	C M3101 A ceed 105°C ion current, the supply o endencies on ambient c	min. -40 -45 ±22.8 270 current IcN (Ic operating temp 22	typ. 550 ±24 ±31 310 @ IP = IPN) i perature ϑ _A	max. +85 +100 ±25.2 375 s lower than I _{SN} . and the value of	Unit °C °C g V mA mA	
$\vartheta_A ^{1)}$ $\vartheta_S ^{m}$ $U_C ^{l}$ $I_{CO} ^{2)}$ $I^{1)}$ The temperatu $I^{2)}$ Due to the Cla The specified w the resistor R _M Sclear ³⁾ Screep ³⁾	Ambi Ambi Mass Supp Curre Curre ss-D final sta vide range of connected Clear Cree	ent operating tem ent storage temp ly voltage ent consumption f ent consumption f nsor surface at any po age used for generatin f the supply current is to the sensor output. rance distance page distance	apperature erature acc. VA for $Ip = 0A$ for $I_{PN} = 1500/$ sition must not ex- ing the compensat reasoned by depen-	C M3101 A ceed 105°C ion current, the supply o endencies on ambient o	min. -40 -45 ±22.8 270 current IcN (Ic: Note the second se	typ. 550 ±24 ±31 310 @ I _P = I _{PN}) i perature ϑ _A	max. +85 +100 ±25.2 375 s lower than I _{SN} . and the value of	Unit °C °C g V mA mA mA	
 ∂_A ¹) ∂_S m U_C I_{C0} I_{C0} I_{C1} ¹) The temperatu ²) Due to the Clar ¹) The specified w the resistor R_M Sclear ³) Screep ³) U_{Sys} ³) 	Ambi Ambi Mass Supp Curre Curre ss-D final sta vide range of connected Clear Clear Creep Syste	ent operating tem ent storage temp oly voltage ent consumption f ent consumption f nsor surface at any po age used for generatin f the supply current is to the sensor output. rance distance page distance em voltage	aperature erature acc. VA or $Ip = 0A$ for $I_{PN} = 1500/$ sition must not ex ag the compensat reasoned by depo	C M3101 A ceed 105°C ion current, the supply o endencies on ambient o	min. -40 -45 ±22.8 270 current Icn (Ic perating temp 22 22	typ. 550 ±24 ±31 310 @ IP = IPN) і: perature 9 _A	max. +85 +100 ±25.2 375 s lower than I _{SN} . and the value of	Unit °C °C g V mA mA mA WRMS	
ϑ _A 1) ϑ _S m Uc Ico IcN ²) ¹⁾ The temperatu ²⁾ Due to the Cla. The specified w the resistor R _M Sclear ³⁾ Screep ³⁾ Usys ³⁾	Ambi Ambi Mass Supp Curre Curre re of the ser ss-D final str vide range of connected Clear Cree Syste	ent operating tem ent storage temp oly voltage ent consumption f noor surface at any po age used for generatin f the supply current is to the sensor output. rance distance page distance em voltage	aperature erature acc. VA or $Ip = 0A$ or $I_{PN} = 1500/$ sition must not ex og the compensat reasoned by deport reinforced insu basic insulatior	C M3101 A ceed 105°C ion current, the supply of endencies on ambient of lation	min. -40 -45 ±22.8 270 current Icn (Ic perating temp 22 22 22	typ. 550 ±24 ±31 310 @ I _P = I _{PN}) i: perature 9 _A .	max. +85 +100 ±25.2 375 s lower than I _{SN} . and the value of 1000 3127	Unit °C °C g V mA mA mA WRMS	
ϑ _A 1) ϑ _S m U _C Ico lcn ²) ¹) The temperatu ²) Due to the Cla The specified w the resistor R _M Sclear ³) Screep ³) U _{Sys} ³)	Ambi Ambi Mass Supp Curre Curre re of the ser ss-D final sta vide range of connected Clear Creep Syste	ent operating tem ent storage temp oly voltage ent consumption f ent consumption f nsor surface at any po age used for generatin f the supply current is to the sensor output. rance distance page distance em voltage	perature erature acc. VA or $Ip = 0A$ or $I_{PN} = 1500/$ sition must not ex og the compensat reasoned by deport reinforced insu basic insulation reinforced insu	C M3101 A ceed 105°C ion current, the supply o endencies on ambient o lation	min. -40 -45 ±22.8 270 current IcN (Ic perating temp 22 22 22	typ. 550 ±24 ±31 310 @ I _P = I _{PN}) i: perature 9 _A	max. +85 +100 ±25.2 375 s lower than I _{SN} . and the value of 1000 3127 1000	Unit °C °C g V mA mA mA WRA VRMS VRMS	
ϑA 1) ϑS m Uc Ico Ico Ico Due to the Cla The specified w the resistor RM Sclear 3) Screep 3) Usys 3)	Ambi Ambi Mass Supp Curre Curre Curre ss-D final sta vide range of connected Clear Creep Syste Work	ent operating tem ent storage temp oly voltage ent consumption f ent consumption f nsor surface at any po age used for generating f the supply current is to the sensor output. rance distance page distance em voltage	aperature erature acc. VA for $Ip = 0A$ or $I_{PN} = 1500/$ sition must not ex reasoned by depo- reinforced insu basic insulation reinforced insu basic insulation	C M3101 A ceed 105°C ion current, the supply o endencies on ambient o lation	<mark>min.</mark> -40 -45 ±22.8 270 силгепt IcN (Ic. opperating temp 22 22	typ. 550 ±24 ±31 310 @ IP = IPN) it	max. +85 +100 ±25.2 375 s lower than I _{SN} . and the value of 1000 3127 1000 4400	Unit °C °C g V mA mA mA WRMS VRMS VRMS VRMS VRMS	
ϑA 1) ϑS m Uc Ico Ico Ico Ico Due to the Cla The specified w the resistor RM Sclear 3) Screep 3) Usys 3)	Ambi Ambi Mass Supp Curre Curre Curre re of the ser ss-D final sta vide range of connected Clear Creep Syste Work	ent operating tem ent storage temp ily voltage ent consumption f ent consumption f nsor surface at any po age used for generatin f the supply current is to the sensor output. rance distance page distance em voltage	aperature erature acc. VA for $Ip = 0A$ or $I_{PN} = 1500/$ sition must not ex registre compensat reasoned by depo- reinforced insu basic insulation reinforced insu basic insulation	C M3101 A ceed 105°C ion current, the supply of endencies on ambient of lation	min. -40 -45 ±22.8 270 current IcN (Ic operating temp 22 22	typ. 550 ±24 ±31 310 @ IP = IPN) i perature θ _A	max. +85 +100 ±25.2 375 s lower than IsN. and the value of 1000 3127 1000 4400 1414	Unit °C °C g V mA mA mA WR WR V RMS VRMS VRMS VRMS VRMS	
ϑA 1) ϑS m Uc Ico IcN 2) 1) The temperatu 2) Due to the Cla The specified w the resistor RM Sclear 3) Screep 3) Usys 3) Usys 3)	Ambi Ambi Mass Supp Curre Curre curre ss-D final st vide range of connected Clear Creep Syste Work Rateo Maxir	ent operating tem ent storage temp oly voltage ent consumption f ent consumption f nsor surface at any po age used for generatin f the supply current is to the sensor output. rance distance page distance em voltage ting voltage d discharge voltage	perature erature acc. VA or $Ip = 0A$ or $I_{PN} = 1500/$ sition must not ex ng the compensat reasoned by deport reinforced insu basic insulation reinforced insu basic insulation ge if erence acc. to	C M3101 A ceed 105°C ion current, the supply of endencies on ambient of lation 1 lation 1 UL 508	min. -40 -45 ±22.8 270 current Icx (Ic perating temp 22 22 22	typ. 550 ±24 ±31 310 @ I _P = I _{PN}) i: perature θ _A	max. +85 +100 ±25.2 375 s lower than I _{SN} . and the value of 1000 3127 1000 4400 1414 1000	Unit °C °C g V mA mA mA VRMS VRMS VRMS VRMS VRMS VRMS VRMS VRMS	
ϑA 1) ϑS m Uc Ico IcN 2) 1) The temperatu 2) Due to the Cla The specified w the resistor Rw Sclear 3) Screep 3) Usys 3) Usys 3) UPD 3) 3) Constructed at Insulation mate	Ambii Ambi Mass Supp Curre Curre re of the ser ss-D final sta vide range of connected Clear Creep Syste Work Rateo Maxir nd manufact erial group 1	ent operating tem ent storage temp oly voltage ent consumption f ent consumption f neor surface at any po age used for generatin f the supply current is to the sensor output. rance distance page distance em voltage discharge voltage discharge voltage mum potential Dif tured and tested in acc , Pollution degree 2, 0	perature erature acc. VA for $Ip = 0A$ or $I_{PN} = 1500/$ sition must not ex- ng the compensat reasoned by depo- reinforced insu basic insulation reinforced insu basic insulation ge if erence acc. to cordance with IEC Dvervoltage categ	C M3101 A ceed 105°C ion current, the supply of endencies on ambient of lation 1 UL 508 control control cont	min. -40 -45 ±22.8 270 current I _{CN} (Ic perating temp 22 22 22	typ. 550 ±24 ±31 310 @ I _P = I _{PN}) i: perature θ _A :	max. +85 +100 ±25.2 375 s lower than I _{SN} . and the value of 1000 3127 1000 4400 1414 1000 orimary opening)	Unit °C °C g V mA mA MA VR VR VRMS VRMS VRMS VRMS VRMS VRMS VRM	
 ∂_A ¹) ∂_S m U_C I_{C0} I_{CN} ²) ¹) The temperatu ²) Due to the Cla The specified w the resistor R_W Sclear ³) Screep ³) U_{SYS} ³) U_{SYS} ³) U_{PD} ³) ³) Constructed at Insulation mate 	Ambi Ambi Mass Supp Curre Curre re of the ser ss-D final sta vide range of connected to connected to Clear Creep Syste Work Rateo Maxir nd manufact erial group 1	ent operating tem ent storage temp oly voltage ent consumption f ent consumption f ent consumption f nsor surface at any po age used for generatin f the supply current is to the sensor output. rance distance page distance em voltage discharge voltage discharge voltage mum potential Dif tured and tested in acc , Pollution degree 2, C	perature erature acc. VA or $Ip = 0A$ or $I_{PN} = 1500/$ sition must not ex og the compensat reasoned by depoint reinforced insu basic insulation reinforced insu basic insulation ge if erence acc. to cordance with IEC Overvoltage categ	C M3101 A ceed 105°C ion current, the supply of endencies on ambient of lation 1 UL 508 : 61800-5-1:2007 (seco ory III, altitude ≤ 2000m	min. -40 -45 ±22.8 270 current I _{CN} (Ic perating temp 22 22 22	typ. 550 ±24 ±31 310 @ I _P = I _{PN}) i: perature θ _A	max. +85 +100 ±25.2 375 s lower than I _{SN} . and the value of 1000 3127 1000 4400 1414 1000 orimary opening)	Unit °C °C g V mA mA MA VR VR VRMS VRMS VRMS VRMS VRMS VRMS VRM	
DA 1) DS M UC Ico ICN 2) 1) The temperatu 2) Due to the Cla The specified w the resistor Rw Sclear 3) Screep 3) Usys 3) UPD 3) 3) Constructed at Insulation mate insulation mate	Ambi Ambi Mass Supp Curre Curre re of the ser ss-D final sta vide range of connected f Clear Cree Syste Work Rateo Maxir nd manufact erial group 1	ent operating tem ent storage temp oly voltage ent consumption f ent consumption f ent consumption f nsor surface at any po age used for generatin f the supply current is to the sensor output. rance distance page distance em voltage discharge voltage discharge voltage discharge voltage mum potential Dif tured and tested in acc , Pollution degree 2, C	perature erature acc. VA or Ip = 0A or I _{PN} = 1500/ sition must not ex og the compensat reasoned by depoint reinforced insulation reinforced insulation ge iference acc. to cordance with IEC Dvervoltage categ	C M3101 A ceed 105°C ion current, the supply of endencies on ambient of lation 1 UL 508 c61800-5-1:2007 (seco ory III, altitude ≤ 2000m	min. -40 -45 ±22.8 270 current I _{CN} (Ic perating temp 22 22 22	typ. 550 ±24 ±31 310 @ I _P = I _{PN}) i: perature θ _A .	max. +85 +100 ±25.2 375 s lower than I _{SN} . and the value of 1000 3127 1000 4400 1414 1000 orimary opening)	Unit °C °C g V mA mA MA VRMS VRMS VRMS VRMS VRMS VRMS VRMS VRMS	

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	Specificatio	on	Item no.:	T60404	·P4640-X256
K-no.: K26928	1700 <i>A</i> for ±24V supply with a	A Current Sensor transformation r	Date:	08.09.2021	
	for electric current measurem DC, AC, pulsed, mixed, wit primary circuit (high power) a				
Customer: Stand	ard type	Customers Part	no.:	Page	2 von 8
Measurement Rar In addition to the senso the actual continuous p (following curves are int	nge Derating r design and construction, following op rimary current I _P , the burden resistor R ierpolated calculations verified by sam	erating parameters ha M, the ambient tempera ple measurements)	ve high influence to the ature ϑ_A , the supply volta	measurement age $\pm U_{C}$ and the set of th	t range limit I _{Pmax} : he busbar temperature.
Derating de	pending on primary current I_P :	De	rating depending on c	onnected bu	rden resistor R_{M} :
$I_{Pmax(DC)} = f$	(I _P) condition: $U_c = \pm 24,0V$ R	_M=1Ω	I _{Pmax(DC)} = f(R _M) co	ndition: U _C =±	:24,0V I _P =1700A







Dwell Time Limits For Maximum DC Currents (IPmax)

ϑ _A	ambient temperature		°C		
Rм	burden resistor	1	5	10	Ω
IPmax(DC)	max. DC primary current	2750	2500	2260	A
t _{dwell}	Permissible dwell time for I _{Pmax(DC)}	< 4	< 6	< 8	minutes

Tab.1: permissible dwell times for measureable DC peak currents at 85°C without degradation of the sensor expected

after higher current loads (Ip > I_{PN}) recovery times should be taken into account.

Absolute Maximum Ratings For Continuous Currents*

ϑ _A	≤ 85°C	* Exposure to this absolute maximum conditions for extended periods may degrade device
RM	≥1Ω	These are stress ratings. Functional operation of the device at these or any other conditions
I _P continuous	≤ 1800A _{DC}	beyond those specified is not supported. This conditions don't comply with UL-Certification.

Tab.2: absolute maximum ratings for continuous currents with not to be excluded degradation and without UL-compliance

Hrsg.: R&D-PD NPI D	Bearb: Ku.	MC-PM: NSch. check		freig.: SB released

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Background information: "bus pumping effect"

For DC and low frequency measurements the output current of the sensor (or so called compensation current) is generated by a class D switching amplifier. the advantages of this thechnology are low power losses, meaning low self-heating of the sensor what makes a continuous measurement of high primary currents possible. Due to the principle of this technology, for $I_P > +300A$ the negative supply current I_{C-} is getting positive and vice versa for $I_P < -300A$ the positive supply current I_{C+} is getting negative as shown in Fig. 5. This effect reaches a maximum/minimum at a certain primary current depending on the operating temperature and the connected burden resistor R_M . It decreases by an increase of R_M or the operating temperature.

- reverse supply currents of the sensor can be used supply (partially) other loads connected to the same power supply

- sensors in three phase systems, where all sensors are connected to one power supply, the supply currents of the sensors can compensate each other similar to the behaviour of load currents in the star point of a three phase system (vector addition).

Hrsg.: R&D-PD NPI D editor	Bearb: Ku.	MC-PM: NSch.		freig.: SB released
		 1.1		

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VACUUMSCHMELZE	;	Specification			T60404-P4	640-X256
K-no.: K26928	Date: 0	8.09.2021				
Customer: Stand	lard type		Customers Part	no.:	Page 6	von 8
Datamatrix Code	specification					
	Code Size: metrical siz symbol size (additionall)	e: 18mm x 18mm e: 24 x 24 points y with a quite zone	around the data ar	ea)		
Standard: ANSI M	IH10.8.2					
1T" Batch-no. "@1	P"Item-no."@	2P"datasheet re	vision"@6D"da	atecode"@10V"prod	duction site"	
1⊤ 0001234567 @	1P T60404-P46	40-X256 @2P 8 1@	⊉6D K36 @10V S	К		
Boutine Test						
Measurement after ter	nperature balance	of the samples at roo	m temperature; SC =	significant characteristic		
K _N (N ₁ /N ₂) (100%	6) M3011/6	Transformation ra	tio (I _P =1500A, 40-8	30 Hz)	1 : 5000 ± 0.3	% (SC)
ls₀ (100% UP (100%	6) M3226 6) M3014	Offset current Test voltage (1s)		2	< 0.1 2.2	mA kV _{RMS}
U _{PDE} (AQL U _{PD(rms)} · 1.875	1/S4)	Pin 1,3,5 to primary Partial discharge * *acc. table 24	opening voltage (extinction))	1500 2813	Vrms Vrms
Type Test						
Preconditioning acc. V	AC M3236 (Pin 1	3,5 to primary openin	g)			
Ûw	M3064	HV transient test	es → polarity +, 5 p	ulses → polarity -)	12	kV
Up	M3014	Test voltage (5s)			4.4	KV RMS
UPDE	M3024	Partial discharge	voltage (extinction))	1500	
* IEC61800-5-1:2007 <u>Applicable docu</u> Constructed, manufac Further standards:	ments and sta tured and tested in UL 508; file E3174	ndards accordance with IEC 83, category NMTR2	61800-5-1:2007. / NMTR8			• TWG
Hrsg.: R&D-PD NP	D Bearb: designer	Ku.	MC-PM: NSch.		fi 	reig.: SB eleased
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VACUUMSCH	IMELZE		Spe	cificatio	n	Item no.:	Т	60404-P	4640-X256
K-no.: ł	<26928		for ±24V sup for electric curre DC, AC, pulsed primary circuit (1700A ply with a tr ent measureme , mixed, with high power) and	Current Sensor ransformation r nt: a galvanic isolation d secondary circuit (r ratio of K_N=1:50 between electronic circuit)	00	Date:	08.09.2021
Custome	r: Stand	ard ty	/pe		Customers Part	no.:		Page 7	von 8
Explanat	ion of the	terms	s used in the da	tasheet				L	
I _{SN:}	Nominal se	econda	ary current (second	lary current valu	ue at I _{PN})				
$X_{total}(I_{PN})$	The sum o by measur	f all po ing a c	ossible errors over current I _{PN} :	the temperature	e range	$X_{total} = 1$	$00 \cdot \left \frac{I_s}{K} \right $	$\frac{I_{\rm PN}}{I_{\rm N} \cdot I_{\rm PN}} - 1$	
X:	Permissibl I _{SB} is the D the same v	e meas C outp value a	surement error in t out current for a DC is the (positive) rat	he final inspect C primary currer ed current I _{PN} (\	ion at RT. ht with with I _O = 0)	X =1	$00 \cdot \left \frac{\mathrm{I}}{\mathrm{I}} \right $	^{SB} – 1	
X _{Ti} :	Temperatu I _{SN} (cf. Not I _{SB} is the	ire drift es on I secon	t of the rated value F _i) in a specified te dary current at ten	orientated outp mperature rang operature ϑ_{A1} or	but term. ge: ΄ ϑ _{A2}	$X_{\mathrm{Ti}} = 1$	$00 \cdot \left \frac{I_{2}}{I_{2}} \right $	$\frac{(\vartheta_{A2}) - I}{I_{SN}}$	$_{\rm SB}(\vartheta_{\rm A1})$
£∟:	Linearity fa output tern	ault wh n. (I _O =	ere I _P is any input 0).	DC and I _{Sx} the o	corresponding	$\mathcal{E}_{L} = 1$	$00 \cdot \left \frac{I_p}{I_{pp}} \right $	$\frac{I_{Sx}}{I_{SN}} - \frac{I_{Sx}}{I_{SN}}$	
Offset, h	nysteresis a	nd dri	ft						
I _{SO:}	Offset curr	ent							
I _{SOH} :	hysteresis sensor by	offset a direc	at Ip=0A, meaning at current of 3 * I_{PN}	secondary current with $R_M = 100\Omega$	rent after overloading	g the			
I _{Ot} :	Long term	drift of	I_0 after 100 tempe	erature cycles ir	n the range -40 to 85	o°C.			
Dynami e ∆t(I _{P,max}):	c properties delay time rectangula output curr	s betwe r prima rent I _s a	en a ary current and the at $I_P = 0.1 * I_{PN}$			۱ _۸ 90%	I _{PN}	t, Is or V _{out}	
t _r :	Response rectangula output curr	time, r r prima rent I _S a	measured as a delatry current and the at $I_P = 0.9 * I_{PN}$	ay time betwee	na	10%	t _a		t
Voltage	ratings	(a	according to IEC 618	00-5-1:2007)					
U _{PD}	Rated disc	harge	voltage (recurring	peak voltage se	eparated by the insu	lation)			
U_{sys}	System vo	ltage:	RMS value of rat	ed voltage					
U _{AC}	Working vo	oltage:	RMS voltage wh	ich occurs by d	esign in a circuit or a	across an insulation			
U _{ACP}	Working vo	oltage	recurring peak	voltage acc. IE0	C 61800-5-1 which o	occurs by design in a	circuit o	r across insu	Ilation.
Hrsg.: R&I editor	D-PD NPI	D	Bearb: Ku.		MC-PM: NSch.				freig.: SB released

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